NSN 5961-00-150-0440

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-150-0440 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.195 inches and 0.205 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.210 inches and 0.225 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.090 inches and 0.110 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.5 on voltage, forward voltage drop, dc and 0.8 gate trigger voltage, dc **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current preset and 200.00 microamperes forward current, total rms preset and 5.00 milliamperes forward current, total rms peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npnp **Test Data Document:** 07148-80860 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No